2SB0767 (2SB767)

Silicon PNP epitaxial planar type

For low-frequency output amplification Complementary to 2SD0875 (2SD875)

■ Features

- Large collector power dissipation P_C
- ullet High collector-emitter voltage (Base open) V_{CEO}
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing

\blacksquare Absolute Maximum Ratings $T_a = 25 ^{\circ}C$

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	-80	V	
Collector-emitter voltage (Base open)	V _{CEO}	-80	V	
Emitter-base voltage (Collector open)	V_{EBO}	-5	V	
Peak collector current	I_{CP}	-1	A	
Collector current	I _C	- 0.5	A	
Collector power dissipation *	P _C	1	W	
Junction temperature	Tj	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	

Note) *: Print circuit board: Copper foil area of 1 cm² or more, and the board thickness of 1.7 mm for the collector portion.

Unit: mm 4.5±0.1 1.6±0.2 3.0±0 3: Emitter 4iniP3-F1 Package

Marking Symbol: 6

■ Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Collector current	Ic	-0.5 A Marking Symbol: C				
Collector power dissipation *	n* P _C 1 W					
Junction temperature T _j 150 °C						
Storage temperature T _{stg} -55 to +150 °C						
Collector power dissipation * P _C 1 W Junction temperature T _j 150 °C Storage temperature T _{stg} −55 to +150 °C Note) *: Print circuit board: Copper foil area of 1 cm² or more, and the board thickness of 1.7 mm for the collector portion. ■ Electrical Characteristics T _a = 25°C ± 3°C						
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = -20 \text{ V}, I_E = 0$			- 0.1	μΑ
Collector-base voltage (Emitter open)	V _{CBO}	$I_C = 10 \mu A, I_B = 0$	-80			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 100 \mu {\rm A}, I_{\rm B} = 0$	-80			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_{\rm E} = -10 {\rm pA}, I_{\rm C} = 0$	-5			V
Forward current transfer ratio *1	h _{FE1} *2	$V_{CE} = -10 \text{ V}, I_C = -150 \text{ mA}$	90		220	
	ch _{FE2}	$V_{CE} = -5 \text{ V}, I_C = -500 \text{ mA}$	50	100		
Collector-emitter saturation voltage *	V _{CE(sat)}	$I_C = -300 \text{ mA}, I_B = -30 \text{ mA}$		- 0.2	- 0.4	V
Base-emitter saturation voltage *	V _{BE(sat)}	$I_C = -300 \text{ mA}, I_B = -30 \text{ mA}$		- 0.85	-1.20	V
Transition frequency	f_T	$V_{CB} = -10 \text{ V}, I_E = 50 \text{ mA}, f = 200 \text{ MHz}$		120		MHz
Collector output capacitance (Common base, input open circuited)	C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		20	30	pF

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

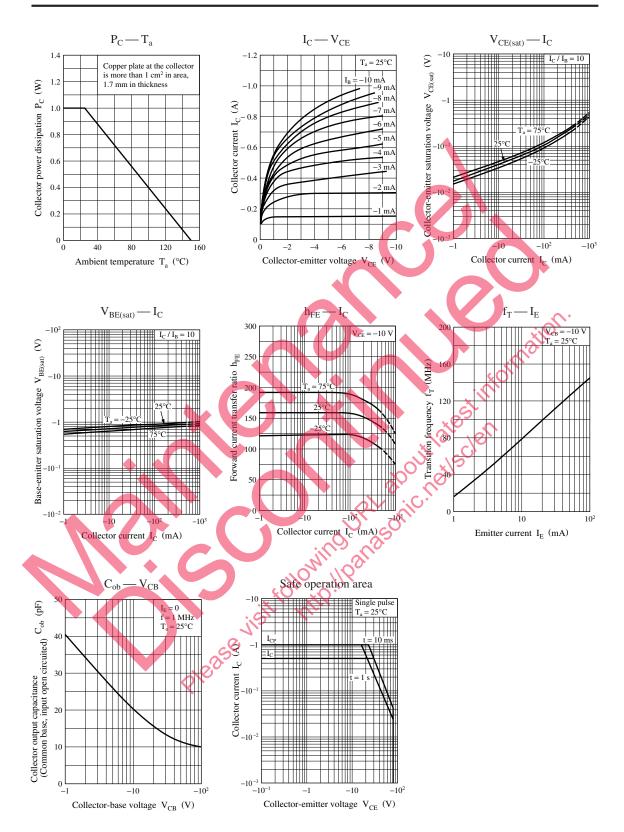
2. *1: Pulse measurement

*2: Rank classification

Rank	Q	R
h _{FE1}	90 to 155	130 to 220

Note) The part numbers in the parenthesis show conventional part number.

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